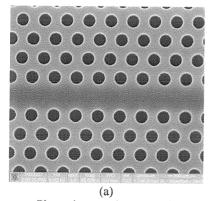
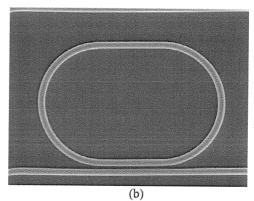
## Fabrication of photonic integrated circuits using high resolution CMOS fabrication process

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Silicon photonics is an attractive platform for wide range of applications. High index contrast and superior material quality enables high-density and low loss photonic integrated circuits. Various optical functionalities such as filtering, modulation are demonstrated on silicon using CMOS compatible fabrication process. CMOS fabrication platform enables mass production thus reducing the cost of the photonic integrated circuits. One of the major advantages of using CMOS fabrication process is the fabrication tools are already in use for fabricating microelectronic circuits. There is no need to develop new tools for fabricating photonic circuits.

Having addressed the advantages of using CMOS fabrication process, one might think, what still holds mass production of photonic integrated circuits. The answer is not simple; one of the major issues is reproducibility of photonic devices. The silicon photonic devices are sensitive to small dimensional changes resulting in change in device response. Roughly 1nm change in the width of a filter will shift the filter peak by 1nm. Hence a high resolution fabrication process is necessary.



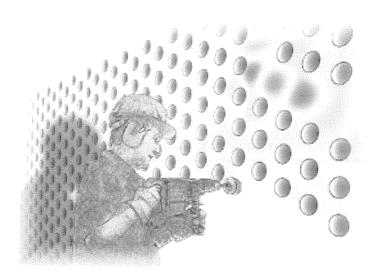


Photonic crystal waveguide (a) and Racetrack ring resonator (b) fabricated using CMOS fabrication process

One of the goals in my research is to address the issue of reproducibility of photonic integrated circuits. The research focuses at high uniformity and reproducibility using advanced CMOS fabrication tools. Studying the source of variation during the fabrication process such as optical lithography and dry etching will result in a scheme to reduce/remove such variations.



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## ABSTRACTS OF POSTERS

## Poster session I:

- 1. V-Groove approach for inverted taper coupling in silicon photonics; J. V. Galán
  - 2. Experimental Study of the Non-Linear Dynamics of Quantum-Dot InAs/InGaAsP/InP (100) Twin-Stripe Lasers Emitting at 1.5µm: Jose Pozo
  - 3. InGaAs-InAlGaAs Monolithically Integrated Temporal Phase Coded OCDMA Encoder/Decoder: S. McMaster
  - 4. A spectrally resolved study of quantum dot lasers: G.A.P. Thé
  - 5. Carrier Transport Effects in Multi Layer Quantum Dot Lasers: M. Rossetti
  - 6. Membrane couplers for optical interconnections on CMOS ICs: A. Morant
  - 7. Optical Losses in Photonic Crystal Waveguides, Induced by Contact Strips for Electrical Pumping: Peter Kaspar
  - Measuring the Time-of-Flight with an optical MEMS-modulator: Joris Roels
  - InP-membrane based photodetector for optical interconnections on Si: P.R.A. Binetti
  - 10. High bandwidth InP-based 1.55 µm waveguide photodetector fabricated in an amplifier layer stack with active-passive integration: L. Xu
  - 11. Design and simulation of movable micromirrors on silicon substrate: Comanescu Florin Constantin
- ♦ 12. Fabrication of polymer-based devices using nanoimprint technology, Jie Teng
  - 13. Liquid crystal technology for wavelength tuning in SOI structures: Wout De Cort
    - 14. Photonic Reservoir Computing: interconnected Semiconductor Optical Amplifiers: Kristof Vandoorne
    - 15. Waveguide grating photonic system analysis for sensor applications: Roxana Ileana Rebigan
    - 16. Design Of A Monolithically Integrated All-Optical Label Swapper For Spectral Amplitude Code Labels Using Cross-Gain Modulation: Christian Habib
    - 17. Combined Technologies: Photolithography and Electron Beam Lithography for RF Filters on GaN Development: Herghelegiu Alexandru
    - 18. Deep dry-etched single-mode narrow waveguide for all-optical switches with InGaAs/AlAsSb quantum wells: Ping Ma
    - 19. Assessment of mesh-interconnected integrated photonic switch circuits: Aaron Albores Meija
    - 20. SOI-based couplers for the transition from DPSK- to DQPSK-demodulators: Karsten Voigt
    - 21. Adjustment of birefringence on Silicon-on-Insulator (SOI) by mechanical bending: Georg Winzer
    - 22. Analysis of thermal crosstalk between DFB-laserdiodes on SOI: B. Wohlfeil
    - 23. Towards optimization of Raman effect in SOI rib waveguides compromise between linear loss and carrier lifetime: Andrzej Gajda
    - 24. Bragg Gratings on SOI Rib Waveguides A Comparison of Different Geometries: Ivano Giuntoni
    - 25. Slow Light in Chalcogenide Photonic Crystals: Marcel Spurny

## Poster session II:

- 26. A comparative study of compact electro-optic modulators based on 1D corrugated waveguide surrounded by Silicon dioxide: Antoine Brimont
- 27. Design and Fabrication of Apodised Crows on Silicon Nitride: J.D. Domenech
- 28. Silicon optical modulator: Fengqiao Dong
- 29. Large Integration Scale Circuits in SiON Technology: Carlo Ferrari
- 30. SOI photonic wires-based devices: sidewall roughness-induced losses and characterization: Antonio Canciamilla
- 31. InP Photonic Crystals bonded to SOI wires: Yacine Halioua & Tim Karle
- 32. Fabrication of photonic integrated circuits using high resolution CMOS fabrication process: Shankar Kumar Selvaraja
- 33. Silicon compatible laser based on colloidal quantum dots: Bram De Geyter
- 34. Al2O3:Er waveguide amplifiers for Si-technology compatible integrated optical applications: L. Agazzi
- 35. Label-free nanophotonic biosensors in silicon based on slot waveguides: Tom Claes
- 36. Design of an integrated electo-optically tunable filter for tunable laser purposes: B.W. Tilma
- 37. Sol-Gel Ormosil-on-Silicon Microphotonics: Paulo Moreira
- 38. 10 Gb/s All-Optical Non-Inverted 1x4 Multi-Wavelength Conversion in a 1.55 μm QD-SOA: J. Herrera
- 39. Photonic Crystal Membrane Type Tunable Nanocavities in InP/InGaAsP: Mehmet Ali Dundar
- № 40. Process Development for passive photonic circuits on BCB- bonded InP membranes on silicon: F. Bordas
  - 41. Novel grating structures for dual-mode laser devices: S. Ginestar
  - 42. Hybrid III-V/Silicon laser based on DVS-BCB die-to-wafer bonding: Stevan Stankovic
  - 43. Fabrication of high brilliance diode lasers in the near-infrared wavelength range: D. Feise
  - 44. The Nanostructuring Platform for Photonic Integration: William Whelan Curtin
  - 45. Design of a reconfigurable optical interconnect for large-scale multiprocessor networks: Iñigo Artundo
  - 46. Photonic crystal waveguides with ring-shaped holes on silicon-on-insulator: A. Säynätjoki
  - 47. **Towards optimizing photonic crystal cavities for Quantum Dot coupling:** Khaled Mnaymneh
  - 48. Quantum Confined Stark Effect (QCSE) Tuned Lasers: Francesca Pozzi
  - 49. Multi-waveguide based collector array for the detection of backscattered light from highly scattering media: N. Ismail
  - 50. Continuous wave InGaAsP/InP Fabry-Perot lasers on silicon: Tiphaine Dupont